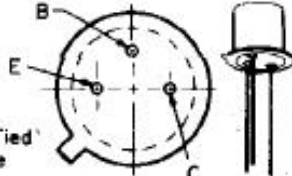


Silicon Small Signal Transistors

(By Case Style and Increasing BV_{CBO}) Maximum Ratings at T_C = 25°C

Breakdown Voltage		Type		Application	Collector Current I _C (A)	Collector Diss. PD (W)	Current Gain hFE	Freq in MHz f _t	Package
BV _{CBO}	BV _{CEO}	NPN	PNP						Case/Basing
75	40	ECG123A		Gen Purp, Amp, Sw	.8	.5	200 typ	300	TO-18 Fig. T2  Collector Tied To Case